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# 20-V N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD15571Q2

## **FEATURES**

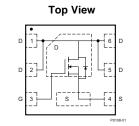
- Ultralow Q<sub>g</sub> and Q<sub>gd</sub>
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 2-mm × 2-mm Plastic Package

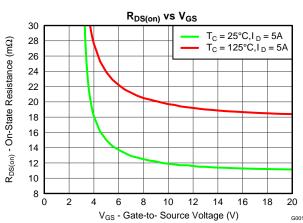
## **APPLICATIONS**

- Optimized for Load Switch Applications
- Storage, Tablets, and Handheld Devices
- Optimized for Control FET Applications
- Point of Load Synchronous Buck Converters

## DESCRIPTION

The NexFET<sup>™</sup> power MOSFET has been designed to minimize losses in power conversion and load management applications. The SON 2x2 offers excellent thermal performance for the size of the package.





## PRODUCT SUMMARY

| V <sub>DS</sub>     | Drain to Source Voltage        | 20                       | V  |    |
|---------------------|--------------------------------|--------------------------|----|----|
| Qg                  | Gate Charge Total (4.5V)       | 2.5                      | nC |    |
| Q <sub>gd</sub>     | Gate Charge Gate to Drain 0.66 |                          |    |    |
| Б                   | Drain to Source On Resistance  | $V_{GS} = 4.5V$          | 16 | mΩ |
| R <sub>DS(on)</sub> | Drain to Source On Resistance  | V <sub>GS</sub> = 10V 12 |    | mΩ |
| V <sub>GS(th)</sub> | Threshold Voltage 1.45         |                          |    |    |

### **ORDERING INFORMATION**

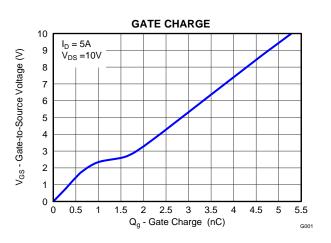
| Device     | Package                            | Media          | Qty  | Ship             |
|------------|------------------------------------|----------------|------|------------------|
| CSD15571Q2 | SON 2-mm × 2-mm<br>Plastic Package | 7-Inch<br>Reel | 3000 | Tape and<br>Reel |

### **ABSOLUTE MAXIMUM RATINGS**

| T <sub>A</sub> = 2                   | 5°C unless otherwise stated   | VALUE      | UNIT |
|--------------------------------------|---|------------|------|
| $V_{\text{DS}}$                      | Drain to Source Voltage   | 20         | V    |
| $V_{\text{GS}}$                      | Gate to Source Voltage  | ±20        | V    |
|                                      | Continuous Drain Current (Package Limit)                            | 22         | А    |
| ID                                   | Continuous Drain Current <sup>(1)</sup>                             | 10         | А    |
| I <sub>DM</sub>                      | Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$                     | 52         | А    |
| PD                                   | Power Dissipation <sup>(1)</sup>                                    | 2.5        | W    |
| T <sub>J</sub> ,<br>T <sub>STG</sub> | Operating Junction and Storage<br>Temperature Range                 | -55 to 150 | °C   |
| E <sub>AS</sub>                      | Avalanche Energy, single pulse I_D = 19A, L = 0.1mH, R_G = 25\Omega | 18         | mJ   |

(1)  $R_{\theta JA} = 50$  on  $1in^2$  Cu (2 oz.) on .060" thick FR4 PCB.

(2) Pulse duration 10µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# **ELECTRICAL CHARACTERISTICS**

#### $T_A = 25^{\circ}C$ , unless otherwise specified

|                     | PARAMETER                        | TEST CONDITIONS                              | MIN TYP   | MAX  | UNIT |
|---------------------|----------------------------------|--|-----------|------|------|
| Static Cl           | naracteristics                   |  |           |      |      |
| BV <sub>DSS</sub>   | Drain to Source Voltage          | $V_{GS} = 0V, I_D = 250\mu A$                | 20        |      | V    |
| I <sub>DSS</sub>    | Drain to Source Leakage Current  | $V_{GS} = 0V, V_{DS} = 20V$                  |           | 1    | μA   |
| I <sub>GSS</sub>    | Gate to Source Leakage Current   | $V_{DS} = 0V, V_{GS} = 20V$                  |           | 100  | nA   |
| V <sub>GS(th)</sub> | Gate to Source Threshold Voltage | $V_{DS} = V_{GS}, I_{DS} = 250 \mu A$        | 1.10 1.45 | 1.90 | V    |
| D                   | Drain to Source On Registeres    | $V_{GS} = 4.5V, I_{DS} = 5A$                 | 16.0      | 19.2 | mΩ   |
| R <sub>DS(on)</sub> | Drain to Source On Resistance    | $V_{GS} = 10V$ , $I_{DS} = 5A$               | 12.0      | 15.0 | mΩ   |
| 9 <sub>fs</sub>     | Transconductance                 | V <sub>DS</sub> = 16V, I <sub>DS</sub> = 5A  | 25        |      | S    |
| Dynamic             | Characteristics                  |  |           |      |      |
| C <sub>ISS</sub>    | Input Capacitance                |  | 320       | 419  | pF   |
| C <sub>OSS</sub>    | Output Capacitance               | $V_{GS} = 0V, V_{DS} = 10V, f = 1MHz$        | 184       | 239  | pF   |
| C <sub>RSS</sub>    | Reverse Transfer Capacitance     |  | 32        | 42   | pF   |
| R <sub>g</sub>      | Series Gate Resistance           |  | 3.8       | 7.6  | Ω    |
| Qg                  | Gate Charge Total (4.5V)         |  | 2.5       | 3.3  | nC   |
| Qg                  | Gate Charge Total (10V)          |  | 5.1       | 6.7  | nC   |
| Q <sub>gd</sub>     | Gate Charge – Gate to Drain      | V <sub>DS</sub> = 10V, I <sub>DS</sub> = 5A  | 0.66      |      | nC   |
| Q <sub>gs</sub>     | Gate Charge Gate to Source       |  | 0.93      |      | nC   |
| Q <sub>g(th)</sub>  | Gate Charge at Vth               |  | 0.52      |      | nC   |
| Q <sub>OSS</sub>    | Output Charge                    | $V_{DS} = 10V, V_{GS} = 0V$                  | 4.1       |      | nC   |
| t <sub>d(on)</sub>  | Turn On Delay Time               |  | 4.7       |      | ns   |
| t <sub>r</sub>      | Rise Time                        | $V_{DS} = 10V, V_{GS} = 4.5V, I_{DS} = 5A$   | 17.2      |      | ns   |
| t <sub>d(off)</sub> | Turn Off Delay Time              | $R_{\rm G} = 2\Omega$                        | 9.9       |      | ns   |
| t <sub>f</sub>      | Fall Time                        |  | 4.1       |      | ns   |
| Diode Cl            | haracteristics                   |  | · · ·     |      |      |
| V <sub>SD</sub>     | Diode Forward Voltage            | $I_{DS} = 5A, V_{GS} = 0V$                   | 0.82      | 1    | V    |
| Q <sub>rr</sub>     | Reverse Recovery Charge          |  | 10.7      |      | nC   |
| t <sub>rr</sub>     | Reverse Recovery Time            | $V_{DD} = 10V, I_F = 5A, di/dt = 300A/\mu s$ | 19        |      | ns   |

## THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

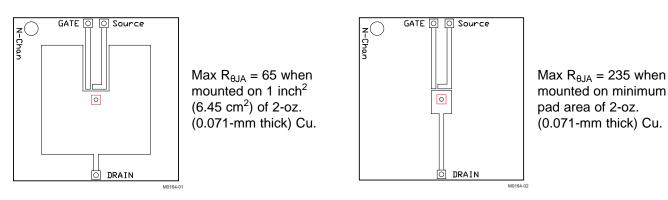
|                       | PARAMETER  | MIN | TYP | MAX | UNIT |
|-----------------------|--|-----|-----|-----|------|
| $R_{	extsf{	heta}JC}$ | Thermal Resistance Junction to Case <sup>(1)</sup>       |     |     | 4.5 | °C/W |
| $R_{\theta JA}$       | Thermal Resistance Junction to Ambient <sup>(1)(2)</sup> |     |     | 65  | °C/W |

(1) R<sub>θJC</sub> is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R<sub>θJC</sub> is specified by design, whereas R<sub>θJA</sub> is determined by the user's board design.
(2) Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.



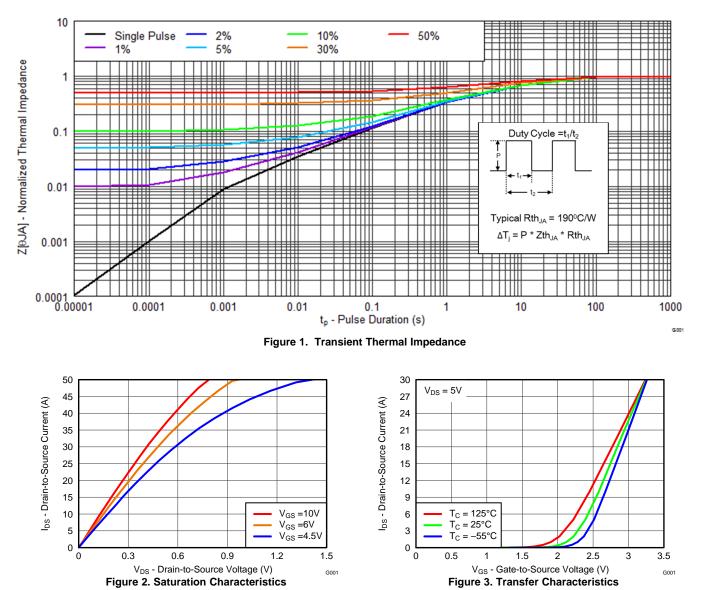
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## **TYPICAL MOSFET CHARACTERISTICS**

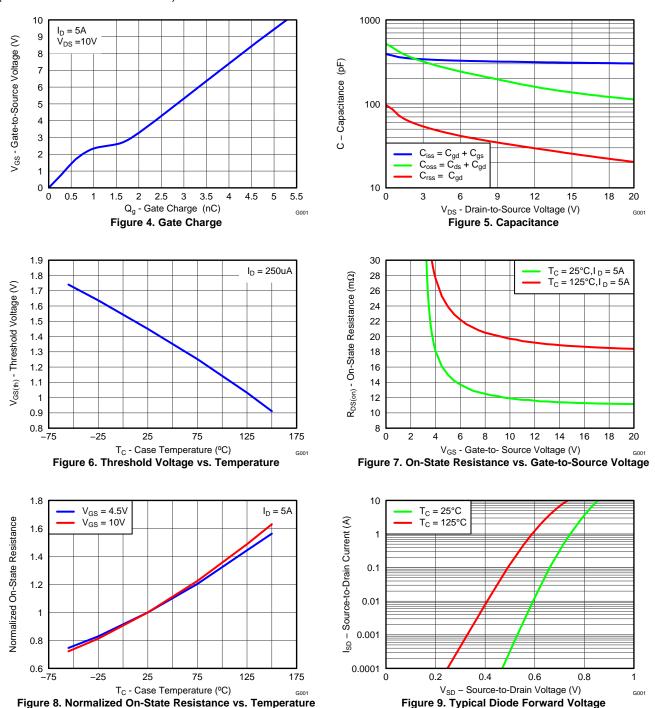
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 



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### **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 



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### **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

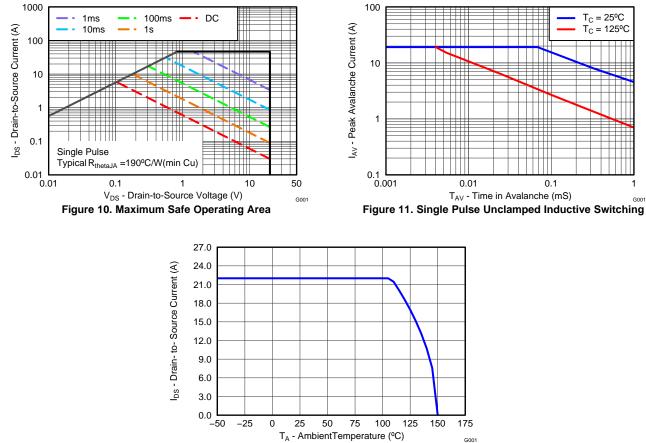


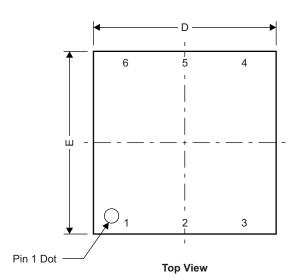
Figure 12. Maximum Drain Current vs. Temperature

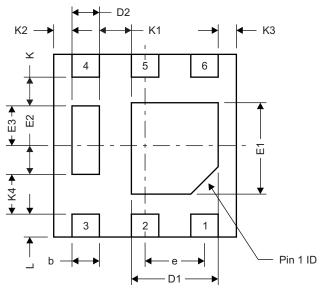
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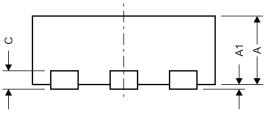
## **MECHANICAL DATA**

## **Q2 Package Dimensions**





Bottom View



Front View

M0165-01

| DIM |       | MILLIMETERS |       |            | INCHES     |       |  |
|-----|-------|-------------|-------|------------|------------|-------|--|
|     | MIN   | NOM         | MAX   | MIN        | NOM        | MAX   |  |
| А   | 0.700 | 0.750       | 0.800 | 0.028      | 0.030      | 0.032 |  |
| A1  | 0.000 |             | 0.050 | 0.000      |            | 0.002 |  |
| b   | 0.250 | 0.300       | 0.350 | 0.010      | 0.012      | 0.014 |  |
| С   |       | 0.203 TYP   |       |            | 0.008 TYP  |       |  |
| D   |       | 2.000 TYP   |       |            | 0.080 TYP  |       |  |
| D1  | 0.900 | 0.950       | 1.000 | 0.036      | 0.038      | 0.040 |  |
| D2  |       | 0.300 TYP   |       | 0.012 TYP  |            |       |  |
| E   |       | 2.000 TYP   |       | 0.080 TYP  |            |       |  |
| E1  | 0.900 | 1.000       | 1.100 | 0.036      | 0.040      | 0.044 |  |
| E2  |       | 0.280 TYP   |       | 0.0112 TYP |            |       |  |
| E3  |       | 0.470 TYP   |       | 0.0188 TYP |            |       |  |
| е   |       | 0.650 BSC   |       | 0.026 TYP  |            |       |  |
| К   |       | 0.280 TYP   |       |            | 0.0112 TYP |       |  |
| K1  |       | 0.350 TYP   |       |            | 0.014 TYP  |       |  |
| K2  |       | 0.200 TYP   |       |            | 0.008 TYP  |       |  |
| K3  |       | 0.200 TYP   |       |            | 0.008 TYP  |       |  |
| K4  |       | 0.470 TYP   |       |            | 0.0188 TYP |       |  |
| L   | 0.200 | 0.25        | 0.300 | 0.008      | 0.010      | 0.012 |  |

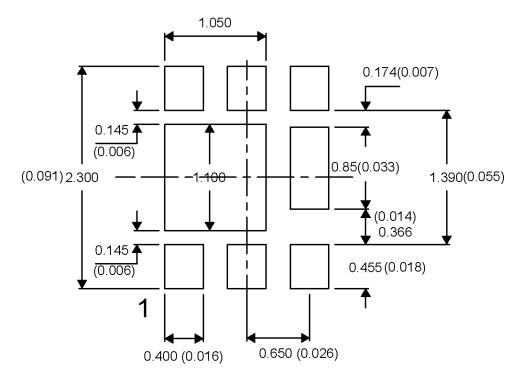
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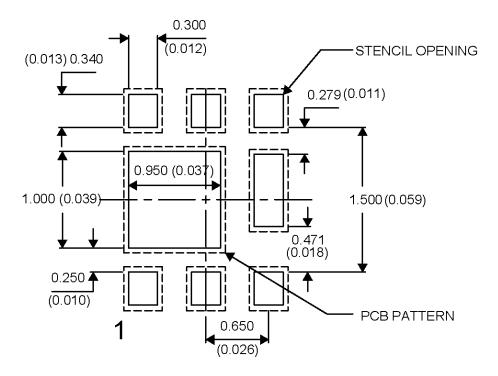
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#### **Recommended PCB Pattern**



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

### **Recommended Stencil Pattern**



Note: All dimensions are in mm, unless otherwise specified.

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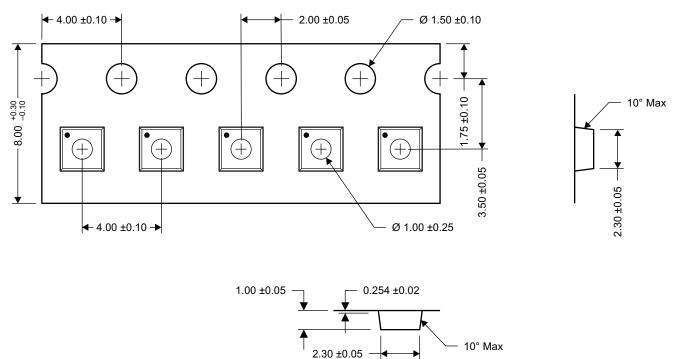
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M0168-01

NSTRUMENTS

**EXAS** 

### **Q2** Tape and Reel Information



Notes: 1. Measured from centerline of sprocket hole to centerline of pocket

- 2. Cumulative tolerance of 10 sprocket holes is ±0.20
- 3. Other material available
- 4. Typical SR of form tape Max 10<sup>9</sup> OHM/SQ
- 5. All dimensions are in mm, unless otherwise specified.



15-Jan-2015

## PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|---------|----------------------------|------------------|--------------------|--------------|----------------|---------|
|                  | (1)    |              | Drawing |      | Qty     | (2)                        | (6)              | (3)                |              | (4/5)          |         |
| CSD15571Q2       | ACTIVE | WSON         | DQK     | 6    | 3000    | Green (RoHS<br>& no Sb/Br) | CU SN            | Level-1-260C-UNLIM | -55 to 150   | 1551           | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

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<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(<sup>6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE OPTION ADDENDUM

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| DLP® Products                | www.dlp.com              | Consumer Electronics          | www.ti.com/consumer-apps          |
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| Clocks and Timers            | www.ti.com/clocks        | Industrial                    | www.ti.com/industrial             |
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